



60V P-Channel Enhancement Mode MOSFET

Voltage

-60 V

Current

-2.4 A

Features

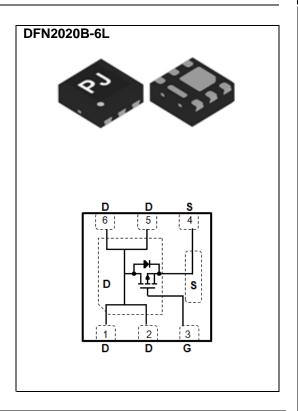
- $R_{DS(ON)}$, $V_{GS}@-10V$, $I_D@-2A<170m\Omega$
- $R_{DS(ON)}$, V_{GS} @-4.5V, I_{D} @-1.5A<220m Ω
- High switching speed
- Improved dv/dt capability
- Low gate charge
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: DFN2020B-6L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0086 grams



$\textbf{Maximum Ratings and Thermal Characteristics} \; (T_A = 25 ^{\circ} C \; unless \; otherwise \; noted)$

PARAMETER	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage	V _{DS}	-60	V		
Gate-Source Voltage		V _{GS}			<u>+</u> 20
Continuous Drain Current (Note 4)	T _A =25°C		-2.4		
	T _A =70°C	l _D	-1.9	Α	
Pulsed Drain Current (Note 1)	I _{DM}	-9.6			
Power Dissipation	T _A =25°C	_	2		
	T _A =70°C	P _D	1.3	W	
Single Pulse Avalanche Energy (Note 6)	Eas	32	mJ		
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient (Note 4,5)		ReJA	62.5	°C/W	





Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-60	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =-250uA	-1.0	-1.88	-2.5			
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-2A	-	140	170	mΩ		
		V _{GS} =-4.5V, I _D =-1.5A	-	190	220			
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V, V _{GS} =0V	-	-	-1	uA		
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA		
Dynamic (Note 7)								
Total Gate Charge	Qg		-	8.3	-	nC		
Gate-Source Charge	Qgs	V _{DS} =-30V, I _D =-2A, V _{GS} =-10V (Note 1,2)	-	1.8	-			
Gate-Drain Charge	Q_{gd}		-	1.6	-			
Input Capacitance	Ciss	. \/ 20\/ \/ 0\/	-	430	-	pF		
Output Capacitance	Coss	V _{DS} =-30V, V _{GS} =0V, f=1MHZ	-	33	-			
Reverse Transfer Capacitance	Crss	I= IIVITZ	-	29	-			
Turn-On Delay Time	td _(on)	$V_{DD}\text{=-}30\text{V}, \ I_{D}\text{=-}1\text{A},$ $V_{GS}\text{=-}10\text{V},$ $R_{G}\text{=}6\Omega \text{ (Note 1,2)}$	-	5.1	-			
Turn-On Rise Time	tr		-	20	-			
Turn-Off Delay Time	td _(off)		-	36	-			
Turn-Off Fall Time	tf		-	11	-			
Drain-Source Diode								
Maximum Continuous Drain-Source	I.			-	-1.5	А		
Diode Forward Current	I _S		-					
Diode Forward Voltage	V _{SD}	Is=-1A, V _{GS} =0V	-	-0.78	-1	V		

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150$ °C. Ratings are based on low frequency and duty cycles to keep initial $T_J=25$ °C.
- 4. The maximum current rating is package limited.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=1mH, I_{AS}=-8A, V_{DD}=-25V, V_{GS}=-10V
- 7. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

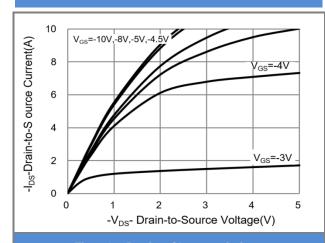


Fig.1 On-Region Characteristics

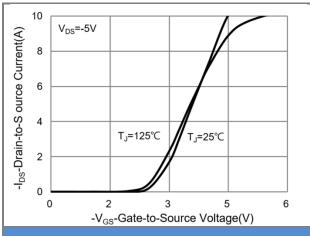


Fig.2 Transfer Characteristics

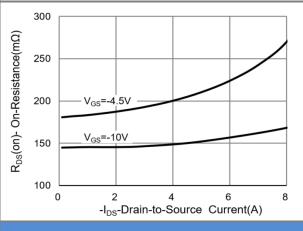


Fig.3 On-Resistance vs. Drain Current

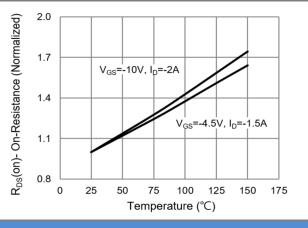
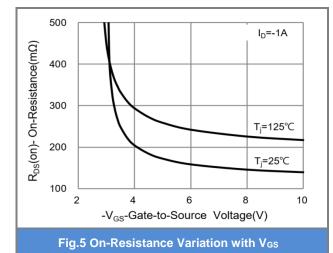
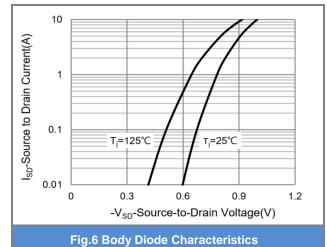


Fig.4 On-Resistance vs. Junction temperature









TYPICAL CHARACTERISTIC CURVES

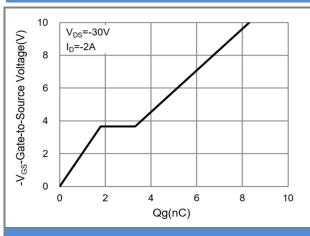


Fig.7 Gate-Charge Characteristics

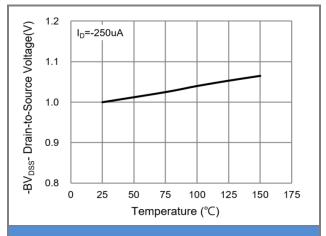


Fig.8 Breakdown Voltage Variation vs. Temperature

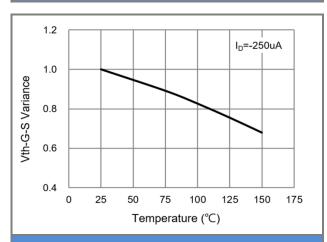


Fig.9 Threshold Voltage Variation with Temperature

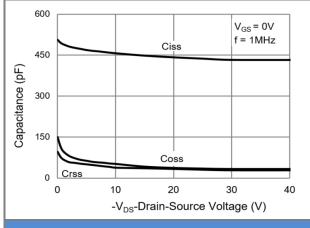
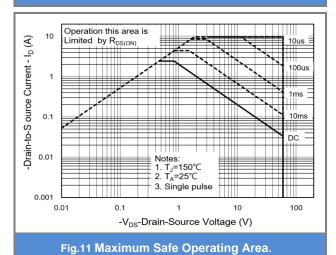


Fig.10 Capacitance vs. Drain-Source Voltage



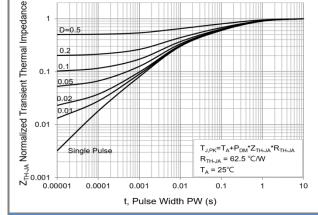


Fig.12 Normalized Transient Thermal Impedance

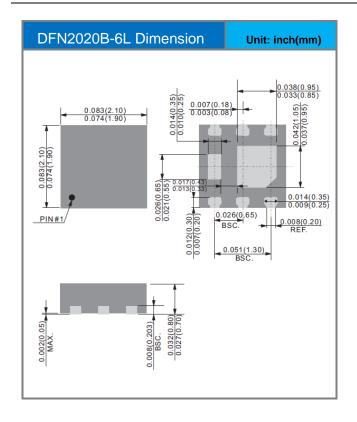


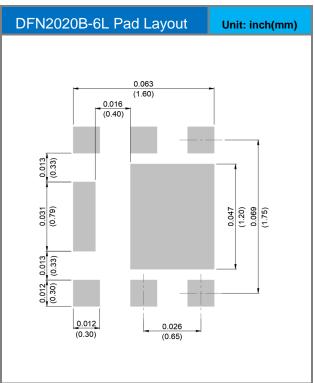


Part No. Packing Code Version

Pa	art No. Packing Code	Package Type	Packing Type	Marking	Version
PJ	JQ2461-AU_R1_000A1	DFN2020B-6L	3K pcs / 7" reel	461	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout









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